



Two-Axis Quantum Control of a Fast Valley Qubit in Silicon

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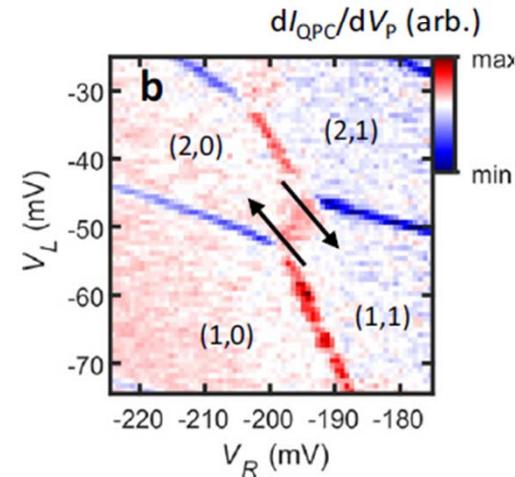
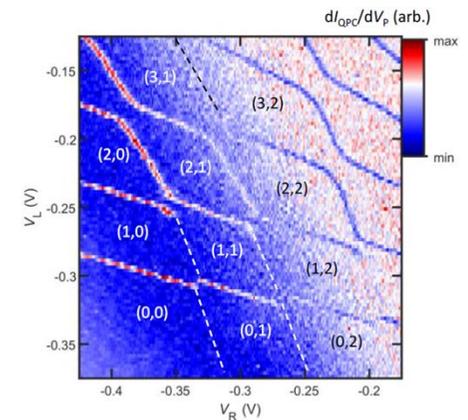
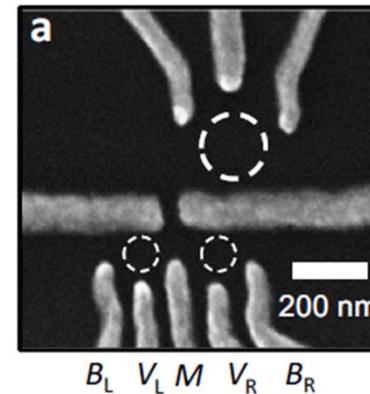
Motivation

- Silicon as a leading contender for hosting qubits
 - Usually spin qubits
 - Nearly degenerate valley states are a possibility for information loss
- Idea: Use of valley states as the qubit
 - Fully electrically controllable (no magnetic field needed)
 - Measured through valley-orbit coupling
 - Large gate voltage space which does not change the valley splitting
 - Could have protection against charge noise
 - Fast gate operation (in order of 10 GHz)
- In this paper
 - Mapping of the surface of the Bloch sphere with sub-nanosecond gate operations



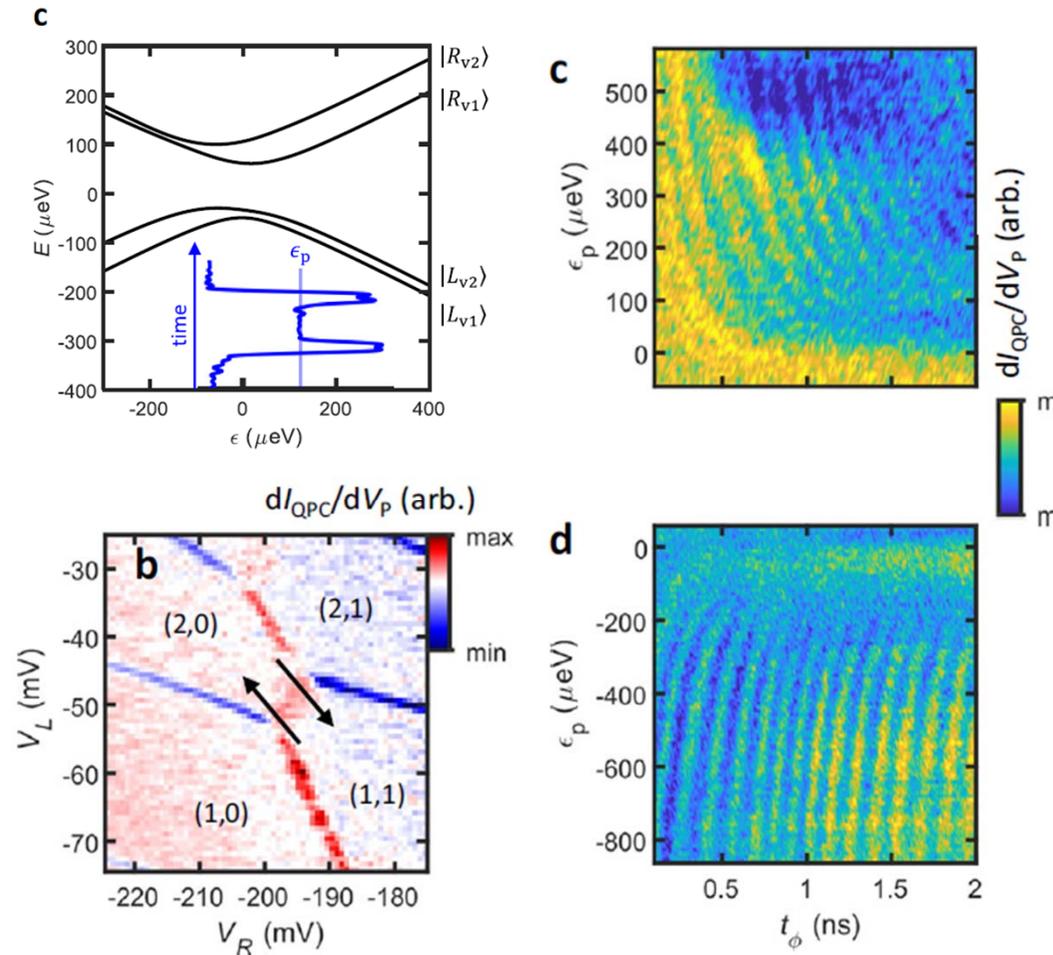
Device

- Double Quantum Dot on a Si/SiGe heterostructure
 - Density: $4 \cdot 10^{11} \text{ cm}^{-2}$
 - Mobility $7 \cdot 10^5 \text{ cm}^2/\text{Vs}$
 - Gate Material: Ti/Au
 - Dielectricum: Al₂O₃
 - Global Top Gate: Aluminium
- Measurements
 - Dilution Refrigerator, base T = 36 mK
 - Voltage Pulses: Agilent 81134 A pulse generator
 - Repetition rate 7.5 MHz



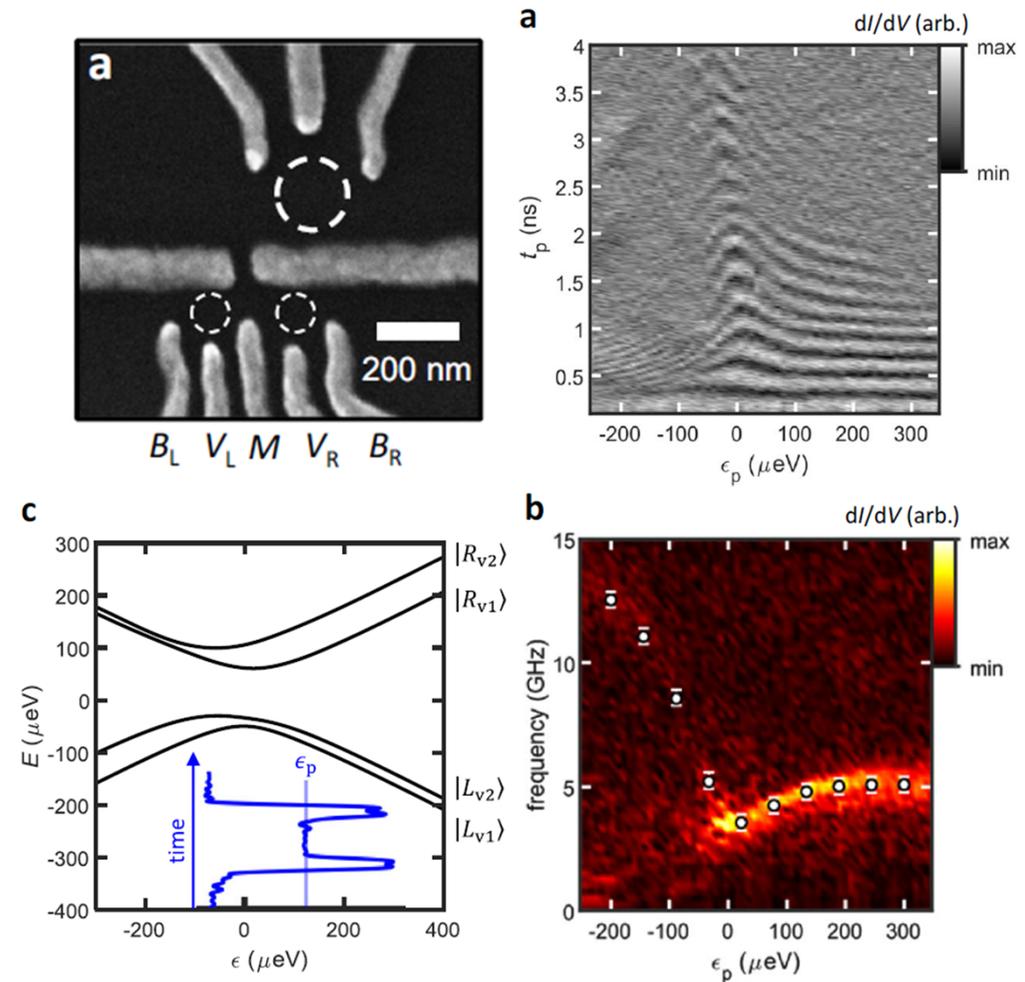
Coherent Valley Oscillations

- Initialization in (1,1) charge configuration ($= |R_{V1}\rangle$)
- Trapezoidal pulse (rise time 200 ps) modifies system detuning $\epsilon = V_R - V_L$
- Anticrossing at $\epsilon \approx 0 \rightarrow$ superposition of two lowest energy states $\psi = 1/\sqrt{2}(|L_{V1}\rangle + e^{i\phi}|L_{V2}\rangle)$
- At maximum detuning: Larmor precession (frequency determined by valley splitting)
- Phase difference mapped to charge states
- Projective readout relies on dot occupation
 - Small valley splitting transformed into large energy difference
- Note: valley splitting modified by spin states, but does not affect charge-based read-out sensitivity
- Lower bound for $T_2^* > 7$ ns (decay of oscillations)



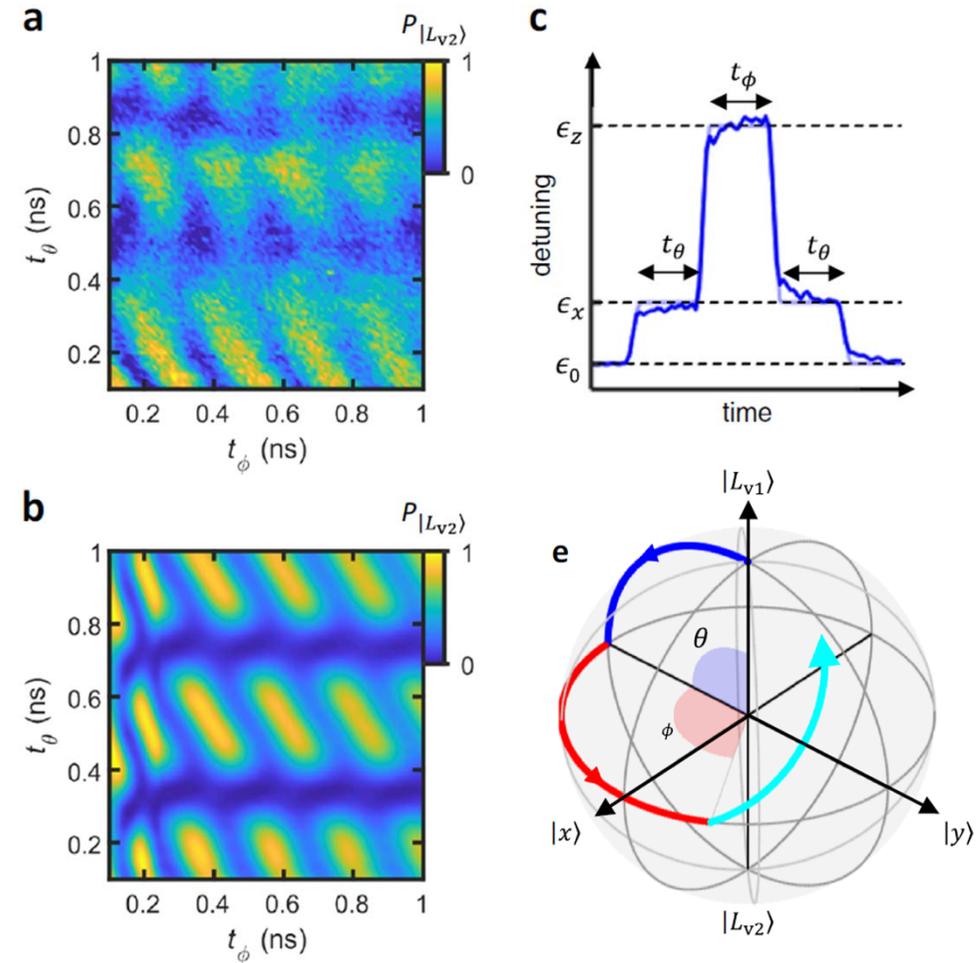
Ramsey Spectroscopy

- Three-stage pulse only on V_R (+ no tunneling out or into dot)
 - High visibility precession
 - Frequency directly convertible to energy gap
 - Valley splittings: $\delta_L = 4.55$ GHz and $\delta_R = 15.7$ GHz
- Sweet spots at $\epsilon = 20$ μeV (first order insensitive to charge noise) and at large detuning (splitting independent of gate voltage)
- Valley splitting varies from dot to dot (10 μeV to 60 μeV)
 - Gate voltages modify up to 20%



Fast Two-Axis Control I

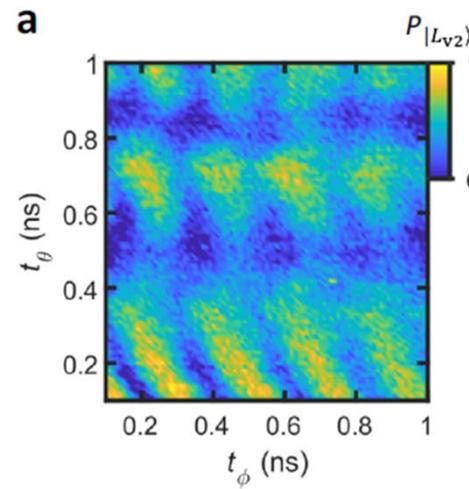
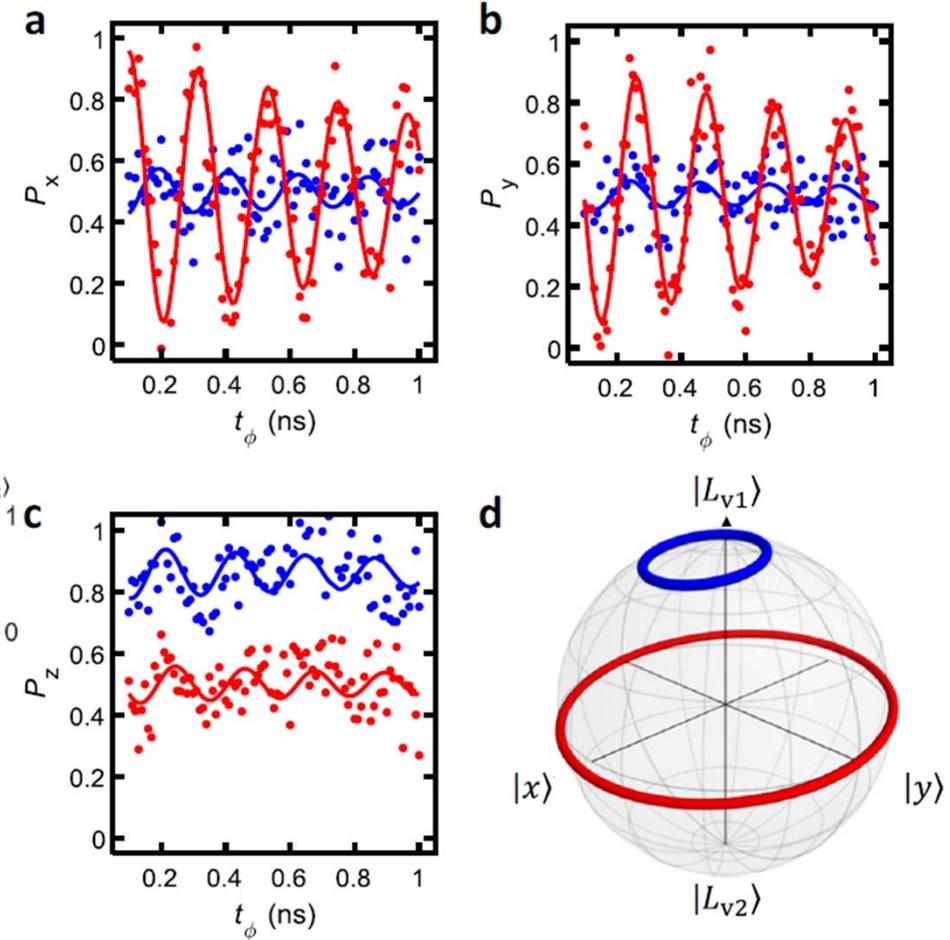
- Three-stage pulse scheme
 - Initialization at $\epsilon_0 = |R_{V1}\rangle$
 - 1. Pulse to ϵ_x = anticrossing, precess for time t_θ
 - 2. Pulse to ϵ_z , precess for time t_ϕ
 - 3. Pulse to ϵ_x , precess for time $t_\theta \rightarrow$ maps valley state to charge state
- Rise time of 200 ps not fast compared to state evolution
 - Rotation occur at an angle $\alpha \sim \pi/4$
- Mapping of the entire surface of Bloch sphere possible [1]
- Note: Mapping is dependent on t_θ due to finite rise time
 - Probability of finding excited state vanishes at even multiples of π (in θ)
- Trace with fixed ϕ : projective measurement of state with initialization and measurement axis determined by t_θ



[1] Previously shown in self assembled quantum dots (Press *et al.* Nature 456, 218-221 (2008), but here the first time in gate defined quantum dots

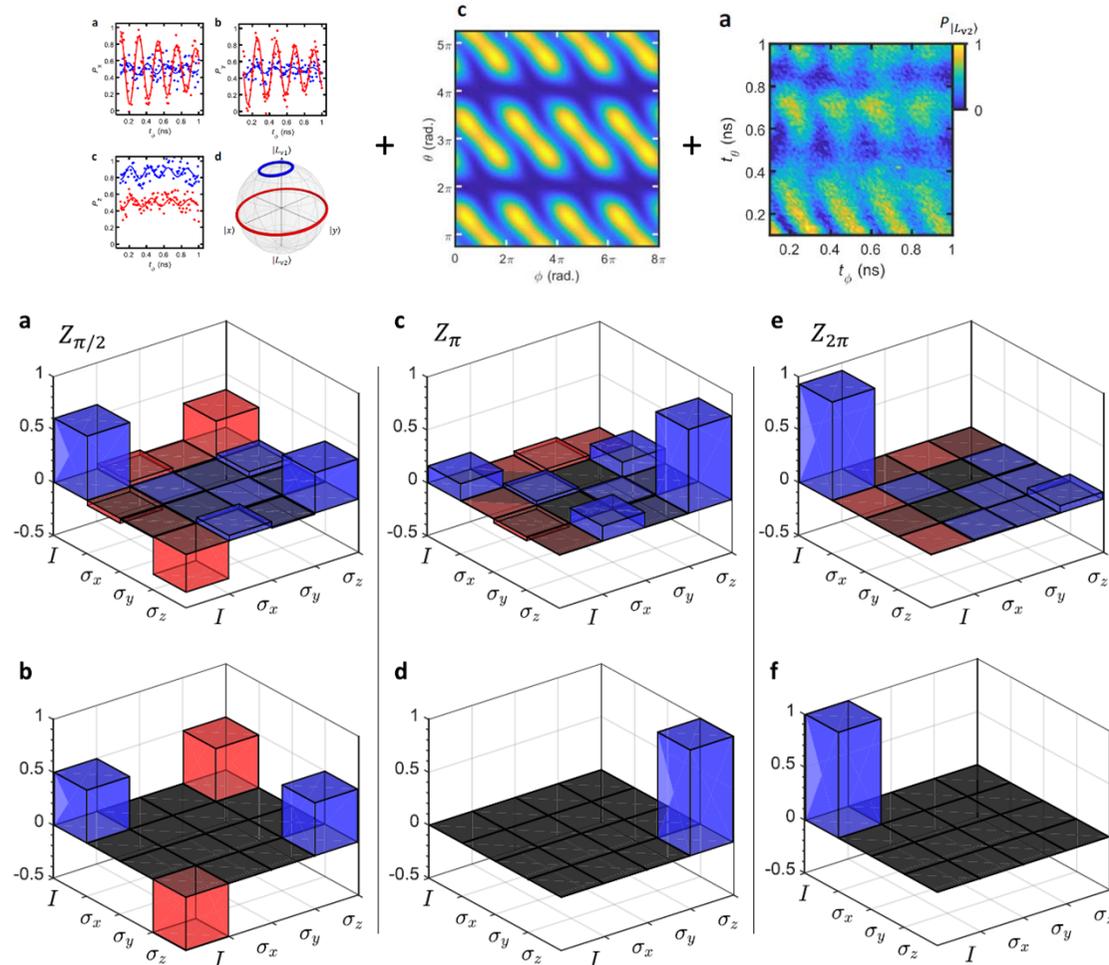
Fast Two-Axis Control II

- Fixing t_θ at 0.22 ns with variable $t_\phi = Z$ rotation in equatorial plane
 - Z rotations have maximum amplitude
- Fixing t_θ at 0.5 ns with variable $t_\phi = Z$ rotation at north pole of bloch sphere
 - Z rotations have minimal amplitude
- Frequencies of rotation agree with energy splitting at operation points



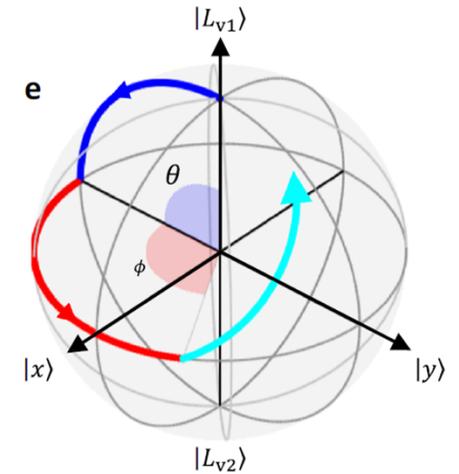
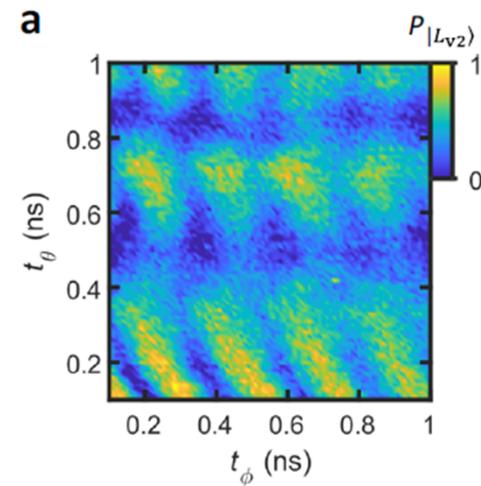
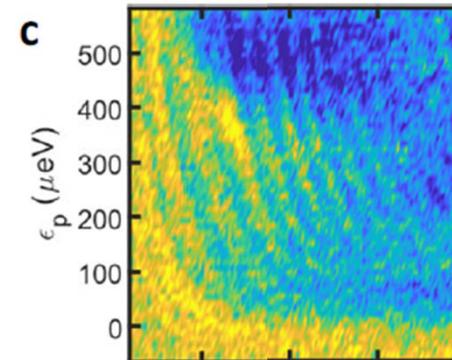
Valley Qubit Operation Fidelities

- Fidelities from quantum process tomography (QPT)
- True QPT not possible due to dynamical projection approach
- Still possible with comparison to theory and reconstruction of states (missing components are approximated)
- $F_{\pi/2} = 85\%$, $F_{\pi} = 79\%$, $F_{2\pi} = 93\%$
- Fidelities limited by rotation axis errors (not decoherence)
- Can be improved with better pulse shaping
- Choice of ϵ_Z has large importance due to converging of energy splitting
 - Charge noise and charge coupling
 - Further supported by coherence time during Z-rotation: 1.5 ns (smaller than typical valley relaxation times)



Summary

- Realization of a valley qubit in a semiconductor
- Fully electrically controlled
- Fast operation (200 – 300 ps)
- Currently inferior to hybrid qubit systems
- Can be improved with proper pulse engineering and detuning



Fast Two-Axis Control III

